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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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PSE Technology Corporation

SPECIFICATION FOR APPROVAL

CUSTOMER	
NOMINAL FREQUENCY	32.768 KHz
PRODUCT TYPE	TYPE G8 SMD CRYSTAL
SPEC. NO. (P/N)	G83270021
CUSTOMER P/N	
ISSUE DATE	Jun.16,2016
VERSION	Α

APPROVED	PREPARED	QA
Brenda	Clane	Dong Jang
APPROVED BY	CUSTOMER:	AVL Status
Please return one copy	with approval to PSE-TW	

PSE Technology Corporation

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VER. A

1-Jun-16

VERSION HISTORY

Version No.	Version Date	Customer Receipt Date	Supplier Receipt Date	Description	Notes
01	Jun.1,2016			New	
02	Jun.2,2016			Updated Temperature Coefficient & C0 Added Reliability	
03	Jun.15,2016			Updated Shunt Capacitance & Motional Capacitance	
А	Jun.16,2016			Release formal version	

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ELECTRICAL SPECIFICATIONS

SRe Part Number: G83270021

Parameters	Symbol	Specifications	Units	Notes
Nominal Frequency	Fn	32.768	KHz	
Frequency Tolerance	FT	± 20	ppm	at 25°C ± 5°C
Load Capacitance	CL	12.5	pF	Тур.
Drive Level	DL	0.1 / 0.5	μW	Typ. / Max.
Equivalent Series Resistance	ESR	70	ΚΩ	Max.
Temperature Coefficient	K	-0.03	ppm/°C ²	± 0.01ppm/°C ²
Operating Temperature Range	TR	-40 to 85	°C	
Shunt Capacitance	C0	1.5	pF	Тур.
Motional Capacitance	C1	6.5	fF	Тур.
Quality Factor	Q	13	K	Min.
Aging		± 3	ppm	Max. 1st year
Storage Temperature Range		-40 to 85	°C	
Insulation Resistance		500	ΜΩ	Min.

Reliability (Mechanical and environmental performances)

No.	Test Items	Conditions	Requirements
1	Bending test	Apply pressure in the direction of the arrow at a rate of about 0.5mm/s until bent width reaches 5mm, and hold for 30 seconds.	Without mechanical damage such as breaks and satisfy sealing specification. Frequency change: Within ±5ppm
2	Shear test	Apply 20N(2.04kgf) static load to the core of quartz crystal units in the direction of the arrow using a R0.5 scratch tool, then hold for 5 seconds.	• Equivalent series resistance(E.S.R) change: Within 5kΩ
3	Core body strength	Apply 10N(1.02kgf) static load to the quartz crystal units center in the direction of the arrow using a R0.5 pushing tool, then hold for 10 seconds.	
4		Frequency sweep method shall be applied as follows. Quartz crystal units shall be vibrated with the sweeping frequency from 10Hz to 55Hz and return to 10Hz in 1 minute, with 1.5mm amplitude. This vibration shall be applied for 2 hours in each 3 perpendicular axes. Other procedures conform to JIS C 60068-2-6.	
5	Shock	Quartz crystal units shall be accelerated at 9810m/s2 by 1ms pulse duration. This shock shall be applied 3 times in each 3 perpendicular axes. Other procedures conform to JIS C 60068-2-27.	

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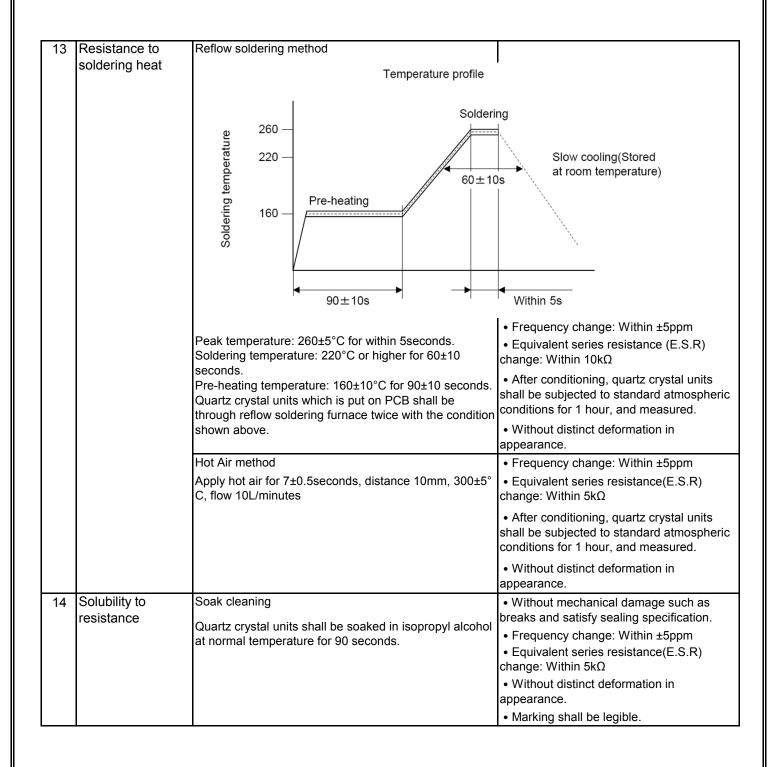
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6	Cold	Quartz crystal units shall be store atmosphere for 1000 hours. Othe to JIS C 60068-2-1.	
7	Dry heat	Quartz crystal units shall be store atmosphere for 100 hours. Other JIS C 60068-2-2.	• After conditioning, quartz crystal units brocedures conform to shall be subjected to standard atmospher conditions for 1 hour, and measured.
8	Damp heat	Quartz crystal units shall be store atmosphere with 90 to 95% relati hours. Other procedures conform	e humidity for 1000
9	Change of temperature	Quartz crystal units shall be subjected of temperature change shapprocedures conform to JIS C 002	wn below. Other
		Temperature	Duration
		1 -40±3°C	30min.
		2 Normal temperature	Within 30 sec.
		3 100±2℃	30min.
		4 Normal temperature	Within 30 sec.
Quartz cr		Both the test methods specified be Quartz crystal units shall be soak	ed in 90°C or higher • Without repetitive leaking bubbles from
		temperature hot water for 5 minut	
		Quartz crystal units shall be teste	by Mass • 1×10-9 Pa·m3/s or less
		rate of helium gas.	measure the leakage
11	Aging		
	Aging Solder-ability	rate of helium gas. Quartz crystal units shall be store	 frequency change: Within ±5ppm Equivalent series resistance(E.S.R) change: Within 5kΩ After conditioning, quartz crystal units shall be subjected to standard atmosphe conditions for 1 hour, and measured.
		rate of helium gas. Quartz crystal units shall be store atmosphere for 720±12 hours. Terminals coated with flux shall be	 d in the 85±3°C Frequency change: Within ±5ppm Equivalent series resistance(E.S.R) change: Within 5kΩ After conditioning, quartz crystal units shall be subjected to standard atmosphe conditions for 1 hour, and measured. e immersed in the Minimum 95% of immersed terminal sl
		rate of helium gas. Quartz crystal units shall be store atmosphere for 720±12 hours. Terminals coated with flux shall be solder bath for 3.5±0.5 seconds.	 Frequency change: Within ±5ppm Equivalent series resistance(E.S.R) change: Within 5kΩ After conditioning, quartz crystal units shall be subjected to standard atmosphe conditions for 1 hour, and measured. Immersed in the Minimum 95% of immersed terminal slip be covered with new uniform solder.
		Terminals coated with flux shall be solder bath for 3.5±0.5 seconds. Items 1 Solder Appropria	 Frequency change: Within ±5ppm Equivalent series resistance(E.S.R) change: Within 5kΩ After conditioning, quartz crystal units shall be subjected to standard atmosphe conditions for 1 hour, and measured. Minimum 95% of immersed terminal slibe covered with new uniform solder. Conditions OAg-0.5Cu ximately 25wt% anol(JIS K 8891) on of resin(JIS K

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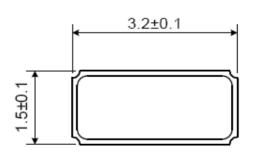
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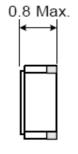
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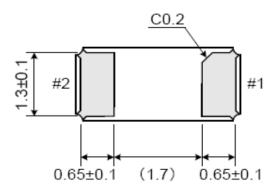
Marking



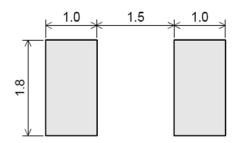
Dimensions (Units: mm)



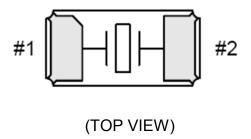




Recommended Soldering Pattern



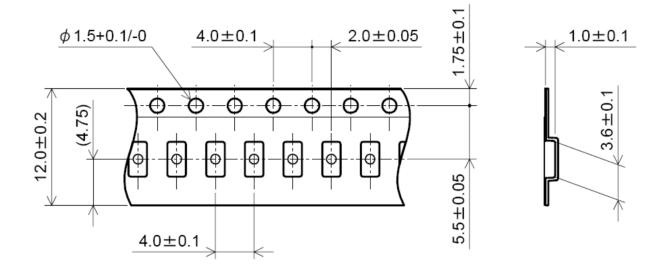
Internal connection



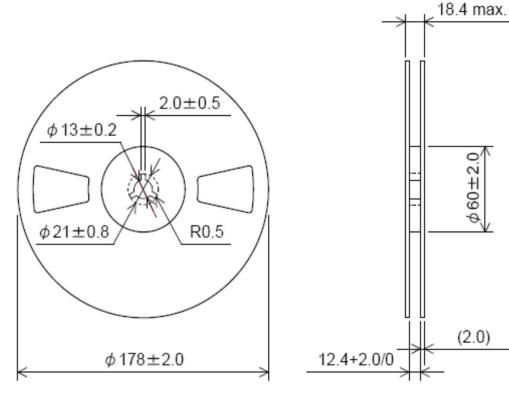
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TAPING (Units: mm)



REEL (Units: mm)



Quantity: 3000pcs / Reel

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